QUICKSWITCH[®] PRODUCTS HIGH-SPEED CMOS QUICKSWITCH 32-BIT MULTIWIDTH[™] BUS SWITCHES

DESCRIPTION:

conventional logic devices.

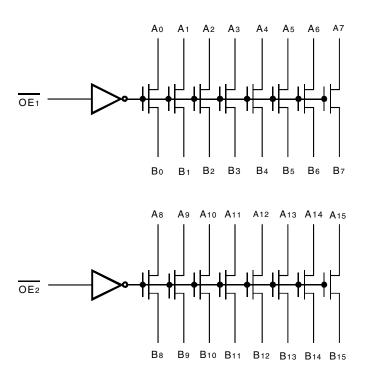
FEATURES:

- · Enhanced N channel FET with no inherent diode to Vcc
- · Bidirectional switches connect inputs to outputs
- Zero propagation delay, zero ground bounce
- QS34X245 is 32-bit version of QS3245
- · Flow-through pinout for easy layout
- · Undershoot clamp diodes on all switch and control inputs
- TTL-compatible control inputs
- Available in 80-pin MilliPaQ[™] package

APPLICATIONS:

- · Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Bus switching and isolation
- · Power conservation
- · Logic replacement (data processing)
- Capacitance isolation
- Clock gating

FUNCTIONAL BLOCK DIAGRAM



B16

The QS34X245 is a member of the MultiWidth™ family of QuickSwitch

devices and provides a set of 32 high-speed CMOS compatible bus switches

in a flow-through pinout. This device is available in the MilliPaQ package,

the world's first small outline 32-bit solution. The low ON-resistance of the

QS34X245 allows inputs to be connected to outputs without adding propa-

gation delay and without generating additional ground bounce noise. When

Output Enable (OEn) is low, the switches are turned on, connecting bus A

to bus B. When OEn is high, the switches are turned off. This device is ideally

suited for 32/64 bit applications where board space is at a premium. QuickSwitch devices provide speeds an order of magnitude faster than

The QS34X245 is characterized for operation at -40°C to +85°C.

A24 A25 A26 A27 A28 A29 A30 A31

B17 B18 B19

B20

B21 B22 B23

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INDUSTRIAL TEMPERATURE RANGE

OCTOBER 2008

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PINCONFIGURATION

	I			$\overline{\mathbf{v}}$			1	
NC		1		Ŭ		80		CC
A0		2				79		E1
A1		3				78	В)
A2		4				77	В	I
A3		5				76	B	2
A4		6				75	В	3
A5		7				74	₿₽	4
A6		8				73	B	5
A7		9				72	В	3
GND		10				71	В	7
NC		11				70		CC
A8		12				69		E2
A9		13				68	В	3
A10		14				67	В	Э
A11		15				66	B	10
A12		16				65	В	11
A13		17				64	B	12
A14		18				63	В	13
A15		19				62	B	14
GND	Γ	20				61	В	15
NC		21				60		C
A16	П	22				59	<u> </u>	E3
A17	Ц	23				58	В	16
A18		24				57	В	17
A19		25				56	В	18
A20	П	26				55	В	19
A21		27				54	B	20
A22		28				53	В	21
A23		29				52	В	22
GND		30				51	В	23
NC		31				50		C
A24		32				49		E4
A25		33				48	В	24
A26		34				47	В	25
A27		35				46	В	26
A28		36				45	В	27
A29		37				44	В	28
A30		38				43	B	29
A31	Ц	39				42	В	30
GND	Ц	40				41	B	31
			MIL	LIP/	10		-	

TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	-0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage Vs	–0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage VIN	–0.5 to +7	V
VAC	AC Input Voltage (pulse width \leq 20ns)	-3	V
Ιουτ	DC Output Current	120	mA
Рмах	Maximum Power Dissipation (TA =70°C)	1.4	W
Tstg	Storage Temperature	-65 to +150	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc.

CAPACITANCE

 $(TA = +25^{\circ}C, f = 1.0MHz, VIN = 0V, VOUT = 0V)$

Pins	Тур.	Max. ⁽¹⁾	Unit
Control Pins	3	4	pF
Quickswitch Channels (Switch OFF)	7	8	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PINDESCRIPTION

Pin Names	Description
ŌEn	Output Enable
An	Data I/Os
Bn	Data I/Os

FUNCTION TABLE(1)

ŌĒn	Function		
Н	Disconnected		
L	An = Bn		

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40° C to $+85^{\circ}$ C, Vcc = $5.0V \pm 5\%$

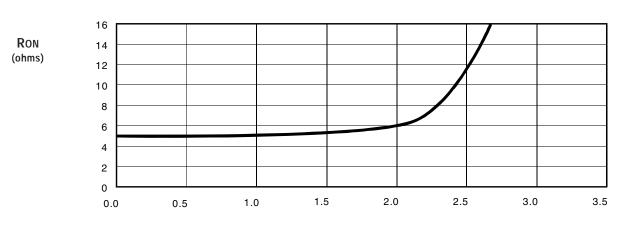
Symbol	Parameter	Test Conditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Level	Guaranteed Logic HIGH for Control Pins	2	_	_	V
Vil	Input LOW Level	Guaranteed Logic LOW for Control Pins	_	_	0.8	V
lin	Input LeakageCurrent (Control Inputs)	$0V \le VIN \le VCC$	_	_	±1	μA
loz	Off-State Current (Hi-Z)	$0V \le VOUT \le Vcc$, Switches OFF	_	_	±1	μA
Ron	Switch ON Resistance	VCC = Min., VIN = 0V, ION = 30mA	—	5	7	Ω
		VCC = Min., VIN = 2.4V, ION =15mA	_	10	15	
Vp	Pass Voltage ⁽²⁾	$V_{IN} = V_{CC} = 5V$, $I_{OUT} = -5\mu A$	3.7	4	4.2	V

NOTES:

1. Typical values are at Vcc = 5.0V, TA = 25° C.

2. Pass Voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs VIN AT Vcc = 5V



VIN (Volts)

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
lcco	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0	12	μA
Δlcc	Power Supply Current per Control Input HIGH ⁽²⁾	Vcc = Max., VIN = 3.4V, f = 0	1.5	mA
ICCD	Dynamic Power Supply Current per MHz ⁽³⁾	Vcc = Max., A and B pins open Control Inputs Toggling at 50% Duty Cycle	0.25	mA/MHz

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per TLL driven input (VIN = 3.4V, control inputs only). A and B pins do not contribute to Δ Icc.

3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_A = -40^{\circ}C \text{ to } +85^{\circ}C, V_{CC} = 5.0V \pm 5\%;$

CLOAD = 50pF, RLOAD = 500Ω unless otherwise noted.

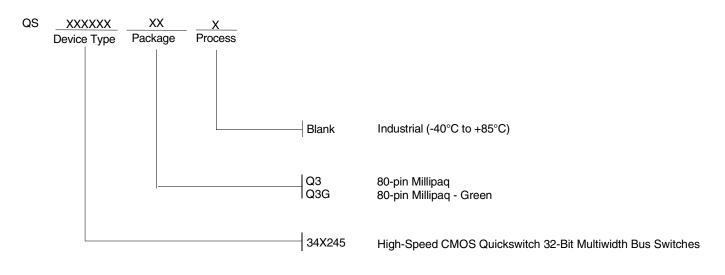
Symbol	Parameter	Min. ⁽¹⁾	Тур.	Max.	Unit
t PLH	Data Propagation Delay ^(1,2)	—	—	0.25	ns
t PHL	An to/from Bn				
tPZL	Switch Turn-on Delay	0.5	—	5.6	ns
tрzн	OE to An/Bn				
tPLZ	Switch Turn-off Delay ⁽¹⁾	0.5	—	5.2	ns
tphz	OE to An/Bn				

NOTES:

1. Minimums are guaranteed but not production tested.

2. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION





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